



1N4001-1N4007

PLASTIC SILICON RECTIFIERS

VOLTAGE 50 to 1000 Volts **CURRENT** 1.0 Amperes

DO-41

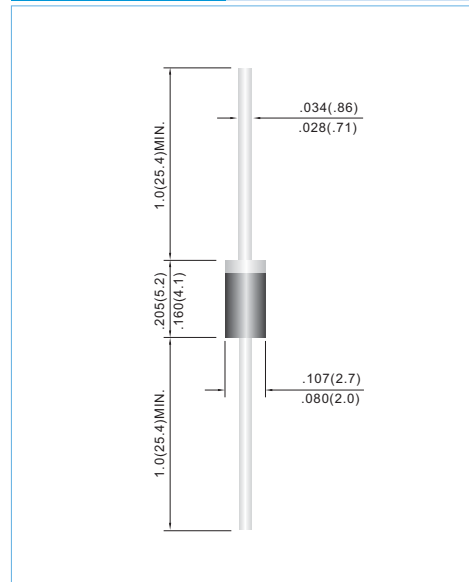
Unit: inch(mm)

FEATURES

- Low forward voltage drop
- High current capability
- High reliability
- High surge current capability
- Exceeds environmental standards of MIL-S-19500/228
- In compliance with EU RoHS 2002/95/EC directives

MECHANICAL DATA

- Case: DO-41 Molded plastic
- Epoxy: UL 94V-O rate flame retardant.
- Lead: Axial leads, solderable per MIL-STD-750, Method 2026
- Polarity: Color band denotes cathode end
- Mounting Position: Any
- Weight: 0.012 ounces, 0.30 gram



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20%.

PARAMETER	SYMBOL	1N4001	1N4002	1N4003	1N4004	1N4005	1N4006	1N4007	UNITS
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	V_{RMS}	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	V_{DC}	50	100	200	400	600	800	1000	V
Maximum Average Forward Current .375"(9.5mm) lead length at $T_A=75^\circ\text{C}$	$I_{F(AV)}$	1.0							A
Peak Forward Surge Current : 8.3ms single half sine-wave superimposed on rated load (JEDEC method)	I_{FSM}	30							A
Maximum Forward Voltage at 1.0A	V_F	1.1							V
Maximum DC Reverse Current at Rated DC Blocking Voltage $T_J=25^\circ\text{C}$ $T_J=100^\circ\text{C}$	I_R	5.0 500							μA
Typical Junction Capacitance (Note 1)	C_J	15							pF
Typical Thermal Resistance (Note 2)	$R_{\theta JA}$ $R_{\theta JC}$ $R_{\theta JL}$	110 40 35							$^\circ\text{C} / \text{W}$
Operating Junction and Storage Temperature Range	T_J, T_{STG}	-55 to +150							$^\circ\text{C}$

NOTES:

1. Measured at 1 MHz and applied reverse voltage of 4.0 VDC.
2. Thermal Resistance from Junction to Ambient and from junction to lead at 0.375"(9.5mm)lead length P.C.B.mounted.



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RATING AND CHARACTERISTIC CURVES

